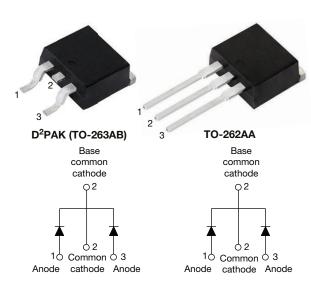
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# VS-MBRB4045CT-M3, VS-MBR4045CT-1-M3

Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 20 A



VS-MBRB4045CT-M3

VS-MBR4045CT-1-M3

PRIMARY CHARACTE	RISTICS
I <sub>F(AV)</sub>	2 x 20 A
V <sub>R</sub>	45 V
V <sub>F</sub> at I <sub>F</sub>	0.58 V
I <sub>RM</sub> max.	95 mA at 125 °C
T <sub>J</sub> max.	150 °C
E <sub>AS</sub>	20 mJ
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA
Circuit configuration	Common cathode

## FEATURES

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation



HALOGEN

FREE

- Center tap TO-220, D<sup>2</sup>PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245  $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

<b>MAJOR RATINGS</b>	AND CHARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I <sub>F(AV)</sub>	Rectangular waveform (per device)	40	А
I <sub>FRM</sub>	T <sub>C</sub> = 118 °C (per leg)	40	A .
V <sub>RRM</sub>		45	V
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	900	A
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.58	V
TJ	Range	-65 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-MBRB4045CT-M3 VS-MBR4045CT-1-M3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	45	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	45	v

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ABSOLUTE MAXIMUM RATI	NGS				
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average per leg		T <sub>C</sub> = 118 °C, rated V <sub>B</sub>		20	
forward current per device	I <sub>F(AV)</sub>	$T_{\rm C} = 110$ C, falled $V_{\rm R}$		40	
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz	z, T <sub>C</sub> = 118 °C	40	А
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	900	
peak surge current per leg	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	rated $V_{RRM}$ applied	210	
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_{J} = 25 \text{ °C}, I_{AS} = 3 \text{ A}, L = 4.4 \text{ m}$	Н	20	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim	•	3	А

ELECTRICAL SPECIFICATI	ONS				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T <sub>.1</sub> = 25 °C	0.60	
Maximum forward voltage drop	V (1)	40 A	1j=25 C	0.78	v
	V <sub>FM</sub> <sup>(1)</sup>	20 A	T 405.00	0.58	
		40 A	T <sub>J</sub> = 125 °C	0.75	
		$T_J = 25 \ ^{\circ}C$		1	
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 100 °C	Rated DC voltage	50	mA
		T <sub>J</sub> = 125 °C		95	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz), 25 °C	900	pF
Typical series inductance	Ls	Measured from top of term	inal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANIC	L SPECIFIC	ATIONS		
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature rar	ge T <sub>J</sub>		-65 to 150	°C
Maximum storage temperature ran	ge T <sub>Stg</sub>		-65 to 175	U
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.5	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, and greased (Only for TO-220)	0.50	°C/W
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation (For D <sup>2</sup> PAK and TO-262)	50	
Approvimeto weight			2	g
Approximate weight			0.07	oz.
Mounting torque	um	Non-lubricated threads	6 (5)	kgf · cm
Mounting torque maxim	um	Non-lubricated threads	12 (10)	(lbf · in)
Marking daylog		Case style D <sup>2</sup> PAK (TO-263AB)	MBRB4	045CT
Marking device		Case style TO-262	MBR40	45CT-1

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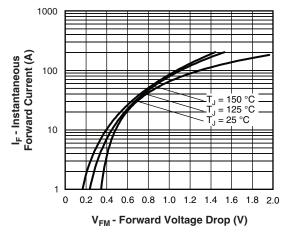
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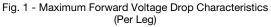
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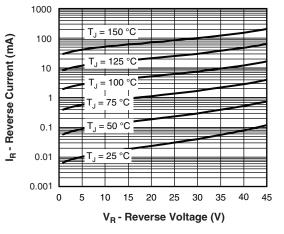


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

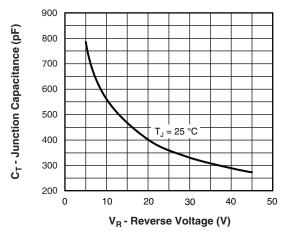


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

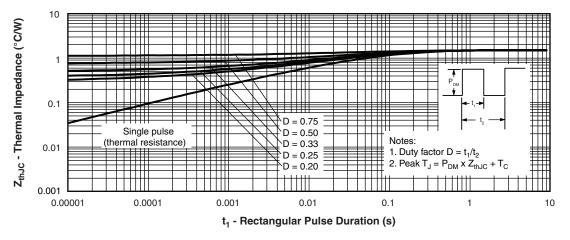


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

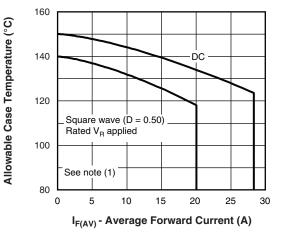
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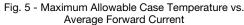
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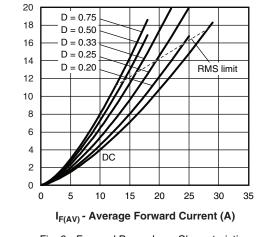


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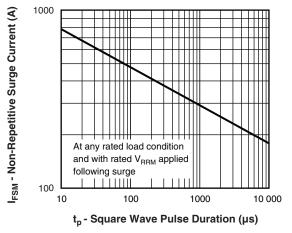
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Average Power Loss (W)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R at V_{R1} = rated V_R$ 

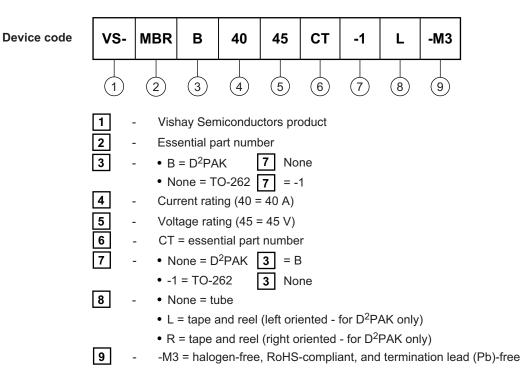


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## **ORDERING INFORMATION TABLE**

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<b>ORDERING INFORMATION</b> (Exan	nple)	
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-MBRB4045CTL-M3	800	13" diameter plastic tape and reel
VS-MBRB4045CT-M3	50	Antistatic plastic tubes
VS-MBRB4045CTR-M3	800	13" diameter plastic tape and reel
VS-MBR4045CT-1-M3	50	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS					
Dimensions -	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions —	TO-262AA	www.vishay.com/doc?96165			
	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information –	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			
SPICE model		www.vishay.com/doc?95296			

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D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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## **Outline Dimensions**



**Vishay Semiconductors** 

**TO-262AA** 

## **DIMENSIONS** in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIMETERS		INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
 <sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

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